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**PLASMA CHEMISTRY**

# **Comparative Study of Degradation of** *trans***-1,3,3,3- Trifluoropropene, 2,3,3,3-Tetrafluoropropene, Perfluoro-3-methylbutanone-2, and Sulfur Hexafluoride in Dielectric-Barrier Discharge**

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**Abstract**—Degradation of gaseous dielectrics after aging in barrier discharge has been experimentally studied and comparative analysis of their properties has been performed. The gases used as gaseous dielectrics have been trans-1,3,3,3-tetrafluoropropene (HFO-1234ze(E)), 2,3,3,3-tetrafluoropropene (HFO-1234yf), perfluoro-3-methylbutanone-2  $CF_3C(O)CF(CF_3)_2$ , and sulfur hexafluoride  $SF_6$ . The product composition of gas degradation before and after 5-h aging in the barrier discharge has been determined by gas chromatogra phy–mass spectrometry and gas chromatography. According to the measurement data, 2,3,3,3-tetrafluoro propene is less prone to degradation and has the highest dielectric strength among the test carbon-containing gases.

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Sulfur hexafluoride  $SF_6$  is widely used in industry and research [1]. In particular, it is used as a gaseous insulator in high-voltage switches of various types. Although  $SF<sub>6</sub>$  is one of the best gases in dielectric strength, a high voltage inevitably gives rise to partial discharges, which gradually lead to degradation of the gas and the occurrence of degradation products [2, 3]. Sulfur hexafluoride itself is nontoxic, but all the prod ucts of its electrical and thermal degradation including those in the presence of other molecules (such as  $H_2O$ ,  $N_2$ , air) are toxic and corrosive [1, 4]. The most toxic products found are  $S_2F_{10}$ ,  $SF_4$ ,  $SO_2F_2$ ,  $SOF_2$ ,  $SOF_4$ ,  $S_2$ OF<sub>10</sub>,  $S_2$ O<sub>2</sub>F<sub>10</sub> [2, 3], F<sub>2</sub>, and HF [5]. This is a disadvantage, since damage of a high-voltage switch results in a release of these gases into the environment, caus ing its pollution by components hazardous to life.

It is also known that  $SF_6$  is one of the most dangerous greenhouse gases, its global warming potential for 100 years is GWP<sub>100</sub> = 23900 at atmospheric lifetime of 3200 years [6]. Greenhouse gas emissions are regu lated by international agreements [7], and  $SF<sub>6</sub>$  substitutes are being actively sought for now.

Currently, the most promising candidates that are acceptable from the environmental point of view

include commercially available hydrofluoroolefins (HFO), in particular, fluorinated propylenes (such as 2,3,3,3-tetrafluoropropene and *trans*-1,3,3,3-tet rafluoropropene) [8, 9]. Hydrofluoroolefins are used as refrigerants, propellants, etc. [9].

The second class of chemicals that meet environ mental requirements is perfluoroketones (CnK, where n is the number of carbon atoms in the molecule). Per fluoro-4-methylpentanone-3 is proposed for use as a flame retardant [10]. Its homologue perfluoro-3 methylbutanone-2 (abbreviated as C5K) is nontoxic and has low values of GWP<sub>100</sub> = 1 and ozone depletion potential  $ODP = 0$ . However, since the boiling point of C5K is as high as  $24^{\circ}$ C, its use as a dielectric gas is possible only in a mixture with  $N_2$  or  $CO_2$ . When a partial discharge is initiated in the insulating medium of high voltage switches, high-frequency current pulses with a nanosecond to microsecond duration occur, aperiodi cally disappearing and appearing again. Revealing the effect of quite rare partial discharges on the properties of the gas takes months of continuous operation. To speed up the research process, gas-filled devices with different electrode configurations, but with the same characteristic electrical fields can be used. In the inter-

electrode gap of the gas-filled working chamber of dielectric barrier discharge (DBD), streamer micro discharges arise, having a structure and physical prop erties similar to those of partial corona discharges in high-voltage switches. Since a DBD streamer locally charges the anode insulator and thus locally reduces the electric field at breakdown, the new streamer can not be generated between the same points on the cath ode and anode surface. The streamers "run" in the interelectrode gap, uniformly penetrating the entire working volume of the gas [11]. This phenomenon gives a considerable gain in gas aging time compared with aging in high-voltage switches, in which the dis charges break down the gas only in the vicinity of the electrodes and are unevenly distributed over the space of the working chamber.

In this study, we investigated the degradation of *trans*-1,3,3,3-tetrafluoropropene (HFO-1234ze(E)), 2,3,3,3-tetrafluoropropene (HFO-1234yf), and per fluoro-3-methylbutanone-2 in a dielectric-barrier discharge in comparison to that of  $SF<sub>6</sub>$ .

## EXPERIMENTAL

The DBD setup consisted of three blocks: the gas– vacuum system designed for prevacuation, admission of a test gas, and sampling after the test; the DBD working chamber; and an electric unit including the power supply and the measuring section. The working chamber was a glass tube (outer diameter, 19 mm; inner diameter, 15.9 mm) with a cylindrical steel elec trode (13.5 mm in diameter and 350 mm in length) inside. The outer electrode was a fine-mesh brass net bearing against the outer surface of the tube. Micro discharges occurred in the space between the tube and the steel electrode surface. The end faces of the glass tube accommodated connections to a pumping line, a gas admission valve, and a pressure gauge. The glass tube simultaneously served as a dielectric barrier and made a closed space to be filled with a test gas.

After evacuating the discharge chamber to After evacuating the discharge chamber to  $\sim 10^{-3}$  atm, a test gas was introduced into it. The working pressure was 1 atm. The discharge tube was con nected in series with a measuring capacitor *CI*. Alter nating voltage was applied across the high-voltage electrode of the discharge tube and the ground  $C_I$ capacitor plate. The capacitance of  $C_I$  (180 nF) was chosen to be much higher than that of the entire elec trode system of the discharge chamber (96 pF), so voltage  $U_I$  on capacitor  $C_I$  was negligible as compared with the voltage drop across the discharge tube [12]. The voltage on the high-voltage electrode was supplied from the high-voltage winding of a power transformer during the entire test-gas aging time. The amplitude of the voltage was controlled with a laboratory autotrans former that set the voltage on the primary winding of the transformer.

The power absorbed by DBD in each test was determined using voltage–charge Lissajous figures. Being proportional to the discharge current, the volt age on capacitor  $C_I$  was recorded at the X input of a GW Instek GDS-71102 oscilloscope. The DBD volt age was measured using a capacitive voltage divider  $C_1-C_2$  (33 nF-33 pF) connected in parallel to the discharge  $C_I$  portion of the circuit. The signal is taken from the midpoint of the divider and is sent to the Y input of the oscilloscope. The power absorbed by the DBD during the feed signal time was determined by measuring the area of the resulting Lissajous figure [12, 13].

Each of the test gases was aged for 5 h with three applied voltages of 2, 6, and 10 kV. The frequency of applied voltage was 50 Hz.

After aging, the gas from the working chamber was sampled using Tedlar bags and gas-tight Hamilton syringes.

The chemicals used in the study were *trans*- 1,3,3,3-tetrafluoropropene (trans-CF<sub>3</sub>CH=CHF) (of 99.96% purity), 2,3,3,3-tetrafluoropropene  $(CF<sub>3</sub>CF=CH<sub>2</sub>)$  (99.0%), perfluoro-3-methylbutanone-2  $(CF_3C(O)CF(CF_3)_2$  (98.7%), and SF<sub>6</sub> (99.9%).

Analyses were performed on a Chrompack CP9000 gas chromatograph. Fluorinated organic compounds were separated on a CP-PoraBOND Q 25 m  $\times$ 0.53 mm capillary column using a flame ionization detector. The composition of the reactant gases and the products of discharge in  $SF_6$  were determined using a thermal conductivity detector (HayeSep Q 80/100 packed column,  $3 \text{ m} \times 2 \text{ mm}$ ). The permanent gases  $H_2$ ,  $O_2$ ,  $N_2$ , CO, and CO<sub>2</sub> were separated on a  $3 \text{ m} \times 2 \text{ mm}$  CarboSieve S-II 80/100 column.

Gas sample components were identified by gas chromatography–mass spectrometry (GC–MS). In operation with fluoroolefins, a Shimadzu analytical instrument (two-dimensional chromatograph) was used. The sample was sequentially separated on Pora- PLOT Q and Supercowax-10 columns and detected in a mass spectrometer. The products of discharge in  $SF_6$ were determined on a Agilent 6890N instrument with a quadrupole mass spectrometer, using a 10 m  $\times$ 0.53 mm poly(trimethylsilylpropyne)-coated analyti cal column (made at the Topchiev Institute [14]).

# RESULTS AND DISCUSSION

Prior to aging in DBD, the composition of the starting materials was examined. The main impurity in *trans*- $CF_3CH=CHF$  was its *cis*-isomer (~0.04 wt %), and the amount of other components was at the level of 0.001 wt %. Impurities in  $CF_3CF=CH_2$  were  $C_2F_4$ (0.17 wt %), trifluoromethylacetylene  $CF_3C\equiv \stackrel{\frown}{CH}$  $(0.004 \text{ wt } %)$ , pentafluoropropane  $CF_3CF_2CH_3$  $(0.72 \text{ wt } %)$ , and an unidentified component  $(0.10 \text{ wt } \%)$ .



Fig. 1. Products of *trans*-CF<sub>3</sub>CH=CHF degradation by aging in DBD at different voltages on the electrodes: (a) residual amounts of (*1*) *trans*-CF<sub>3</sub>CH=CHF and (*2*) CF<sub>3</sub>CF=CH<sub>2</sub> (given for comparison); (b) (*3) cis*-CF<sub>3</sub>CH=CHF, (*4*) unidentified products, (5)  $CF_3C=CH$ ; (c) (6)  $C_2F_4$ , (7)  $CF_4$ , (8)  $C_2F_6$ , (9)  $CF_3CF=CH_2$ , (10)  $C_2HF_5$ ; and (d) (11)  $CF_2=CHF$ , (12)  $CF_2=CH_2$ ,  $(13)$  C<sub>3</sub>F<sub>8</sub>,  $(14)$  C<sub>3</sub>F<sub>6</sub>.

During aging in DBD, fluoroolefins undergo deg radation and condensation and gaseous products and polymer films are built up. The main gaseous products of *trans*-CF<sub>3</sub>CH=CHF degradation under these conditions are the olefin isomer *cis*-CF<sub>3</sub>CH=CHF and trifluoromethylacetylene  $CF_3C \equiv CH$  (Fig. 1b). All quantities in Figs.  $1-3$  are in given in weight percent based on only one element carbon (wt % carb.). The main gaseous products of the  $CF_3CF=CH_2$  decomposition in DBD are *trans*-CF<sub>3</sub>CH=CHF and  $CF_3C\equiv CH$  (Fig. 2).

According to the analysis data, the yield of *trans*-  $CF_3CH=CHF$  and  $CF_3CF=CH_2$  degradation products significantly increases with an increase in voltage across the DBD electrodes from 2 to 6 and further to 10 kV. The only exception is the formation of *cyclo*-  $C_4F_8$  at  $U = 2$  kV for  $CF_3CF=CH_2$ . At a voltage of 10 kV, the number of products is significantly greater, with the decay and destruction processes to form the perfluoroalkanes  $CF_4$ ,  $C_2F_6$ , and  $C_3F_8$ ; tetrafluoroethylene  $C_2F_4$ ; and other fluoroolefins becoming more intense. According to the results of GC–MS analysis in the selected ion monitoring (SIM) mode, there was no perfluoroisobutene in the products of both test gases.

Determining on the CarboSieve S-II chromato graphic column the products of degradation of both of the initial hydrofluoroolefins under severe conditions  $(U = 10 \text{ kV})$ , we found that they contained H<sub>2</sub>  $(\sim 0.5 \text{ vol } \%)$ , CO  $(\sim 1.7 \text{ vol } \%)$ , and CO<sub>2</sub>  $(0.7 0.8$  vol  $\%$ ).

During the aging of both hydrofluoroolefins, a pressure drop in the reactor by ~250 torr was detected. The pressure dropped proportionally to the time. This behavior is obviously due to film deposition on the inner surfaces of the reactor. The formation of fluoro carbon films from fluorinated compounds with a high C/F ratio during gas-phase etching is known from the literature [6].

Elemental analysis of samples of the films depos ited during *trans*-CF<sub>3</sub>CH=CHF degradation in DBD was performed using the dynamic flash combustion method involving the subsequent gas chromatographic



Fig. 2. Products of CF<sub>3</sub>CF=CH<sub>2</sub> degradation by aging in DBD at different voltages on the electrodes: (a) (1) *trans*- $CF_3CH=CHF$ , (2)  $CF_3C=CH$ , (3) *cis-CF*<sub>3</sub>CH=CHF; (b) (4)  $CF_3CF_2CH3$ , (5) unidentified products, (6) *cyclo-C*<sub>4</sub>F<sub>8</sub>; (c) ( $7\text{C}_2\text{F}_4$ , ( $8\text{C}_4\text{F}_4$ , ( $9\text{C}_2\text{F}_2=\text{CH}_2$ , ( $10\text{C}_2\text{F}_6$ ; and (d) ( $11\text{C}_2\text{F}_2=\text{CHF}_5$ , ( $12\text{C}_3\text{F}_8$ , ( $13\text{C}_2\text{HF}_5$ , ( $14\text{C}_3\text{F}_6$ .)

determination. The results of the study are presented in Table 1. It is seen that analytically undetectable ele ments make about 60%. Assuming that they are mainly represented by fluorine, the chemical element that is part of the starting hydrofluoroolefin, we find that the film has the  $C_2HF_2$  composition. Such a composition suggests the presence of two types of carbon structures in the polymer, the chain  $(CX_2-CX_2)$ or  $(CX_2-CX(CX_3))$  structure and the planar  $(CX)$ = structure in approximately equal amounts, where  $X = H$  or  $F$ .

The data in Fig. 1a show that at voltages of 6 and 10 kV, the residual amount of *trans*-CF<sub>3</sub>CH=CHF is noticeably smaller than that of  $CF_3CF=CH_2$ . At the same drop in pressure of the starting hydrofluoroolefin in the reactor, this means that the degree of conversion of *trans*-CF<sub>3</sub>CH=CHF is higher under comparable conditions.

The main channels of *trans*-CF<sub>3</sub>CH=CHF conversion in a barrier discharge is isomerization to *cis*-  $CF<sub>3</sub>CH=CHF$  and 1,2-dehydrofluorination:

 $trans\text{-}CF_3CH=\text{-}CHF \rightarrow cis\text{-}CF_3CH=\text{-}CHF$ ,  $trans\text{-}CF_3CH=\text{-}CHF \rightarrow CF_3C=\text{-}CH + HF.$ 

It is known that the geometric isomerization of hydrofluoroolefins occurs at a high rate; for example, the pre-exponential factor of the rate constant for the trans–cis isomerization of 1,2-difluoroethylene

Table 1. Results of elemental analysis of the polymer produced in DBD treatment of HFO-1234ze(E)

Sample name	Element determined and measurement units				
	Nitrogen, $%$	Carbon, $%$	Hydrogen, %	Sulfur, $\%$	
Condensate from discharge	$0.11\,$	38.9	. 58	0.60	

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**Fig. 3.** Products of C5K degradation by aging in DBD at different voltages on the electrodes: (a) (*1*) C5K; (b) (*2*) CF<sub>3</sub>COOCH<sub>3</sub>, (3)  $CF_3COOCF_3$ ; (c) (4)  $C_3F_6$ , (5)  $C_3F_8$ , (6)  $CF_2=CF-CHF_2$ , (7)  $C_2F_6$ , (8)  $CF_4$ ; and (d) (9, 12)  $C_4F_{10}$ , (10, 11)  $C_6F_{14}$ ,  $(12)$  C<sub>4</sub>HF<sub>5</sub>,  $(13)$  C<sub>5</sub>F<sub>12</sub>.

CHF=CHF is  $log A = 12.98$  and the activation energy is  $E_a = 60.1 \text{ kcal/mol}$  [15].

In contrast to *trans*-CF<sub>3</sub>CH=CHF, geometric isomerism is not inherent in  $CF_3CF=CH_2$  and, hence, there is no trans–cis isomerization reaction, a prop erty that is beneficial to the stability of the molecule (Fig. 1a). The main channels of  $CF_3CF=CH_2$  conversion in barrier discharge are isomerization into *trans*-  $CF<sub>3</sub>CH=CHF$  and 1,2-dehydrofluorination:

$$
CF_3CF=CH_2 \rightarrow trans-CF_3CH=CHF,
$$

$$
CF_3CF=CH_2 \rightarrow CF_3C\equiv CH + HF.
$$

The 1,2-dehydrofluorination of fluoroolefins (flu oroethylene and 1,1-1,1-difluoroethylene) typically requires approximately 80 kcal/mol [16–19]. The dehydrofluorination of either hydrofluoroolefin results in the formation of one HF molecule per mol ecule of trifluoroacetylene  $CF_3C=CH$ . Using IR spectrometry, we failed to detect HF traces in the hydrofluoroolefin degradation products. Most likely, HF had reacted with the glass walls of the discharge tube or the IR optical cell as early as the aging process in DBD or gas sampling, respectively. The interaction of HF with trifluoroacetylene would give different hydrofluoroolefins. For example, the DBD in  $CF_3CF=CH_2$  will result in both  $CF_3CH=CHF$  isomers (*trans*- and *cis*- in a 9–10/1 ratio).

In the case of aging of hydrofluoroolefins in DBD under severe conditions, carbon oxides  $CO$  and  $CO<sub>2</sub>$ were detected in the product mixture. The oxygen required for their formation could be produced in the discharge by reacting HF with the glass walls of the barrier discharge tube.

Initial perfluoro-3-methylbutanone- $(C5K)$ contained methyl trifluoroacetate  $CF<sub>3</sub>COOCH<sub>3</sub>$  $(-1.3 \text{ wt } %)$  and a very small amount of water vapor H<sub>2</sub>O ( $\sim$ 0.05 wt %) as impurities.

According to the analysis data, the main products of the process are hexafluoropropene  $C_3F_6$ , 1,1,2,3,3pentafluoropropene  $CF_2=CF-CHF_2$ , perfluorobutane  $C_4F_{10}$ , and perfluoro(methyl acetate)  $CF<sub>3</sub>COOCF<sub>3</sub>$  (Fig. 3).

The pressure drop in the working chamber at an applied voltage of 6 or10 kV was a few torr, which is considerably lower than in the case of hydrofluoroole-

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Mixture after aging in DBD	Voltage across DBD electrodes				
	$2$ kV	6 kV	$10 \text{ kV}$		
$HFO-1234ze(E)$			CO (1.68), $C_3F_6$ (0.02), $CF_3CCH$ (0.86)		
$HFO-1234$ yf			CO (1.73), $C_3F_6$ (0.11), CF <sub>3</sub> CCH (2.58)		
C5K	$C_3F_6(0.03)$	$C_3F_6(0.01)$	$C_3F_6(0.89)$ , CO (4.96)		
SF <sub>6</sub>		$S_2F_{10}+S_2OF_{10}(1.7)$	$\rm{S}F_4$ (0.07), $\rm{S_2F_{10} + S_2OF_{10}}$ (21.2)		

Table 2. Results of GC and GC--MS analysis of toxic degradation products of test gases (vol. %)

**Table 3.** Degradation products of  $SF<sub>6</sub>$  after aging in DBD at different voltages on the electrodes

$U,$ kV	$O_2/N_2/Ar/CO$	SF <sub>4</sub>	CO <sub>2</sub>		$ SF_6 + SO_2F_2 S_2F_{10} + S_2OF_{10} $	$H_2O$	Unidentified product	Total
	0.05	0.00	0.00	99.94	0.00	0.014	0.00	100.00
	0.05	0.00	0.04	96.89	2.88	0.14	0.00	100.00
10	0.05	0.05	0.39	66.17	32.9	0.33	0.10	100.00

fins. Nonetheless, there was also film deposition on the electrode and the glass tube.

The initial sample of sulfur hexafluoride  $SF_6$ (99.986 wt %) contained a small amount of water vapor  $H<sub>2</sub>O$  (0.014 wt %). According to GC–MS data, there were no impurities in  $SF<sub>6</sub>$ , other than water vapor.

The barrier discharge in  $SF_6$  is ignited at 3.7 kV. Table 3 shows changes in the product composition of the test gas before and after testing at voltages of 6 and 10 kV. Note that the proportion of oxygen-containing compounds, such as  $CO<sub>2</sub>$  and  $H<sub>2</sub>O$ , increases.

Toxicity of the mixtures after aging in DBD is an important issue in the assessment of the properties of the test gases. The chemical analysis of the degrada tion products of the test gases showed that the C5K ketone degradation products contain the toxic com ponent  $C_3F_6$  even at a voltage of 2 kV. At 10 kV, the amount of CO in the degradation products of this gas is three times that in the degradation products of the olefins (Table 2). This difference is obviously due to the fact that oxygen is not inherently a part of the ole fins, but it is the product of HF reaction with glass of the discharge tube. However, a significant amount of  $CF<sub>3</sub>$ C≡CH was found in the olefins after DBD treatment at 10 kV and, therefore, the hydrofluoroolefins HFO-1234yf and HFO-1234ze(E) cannot be recom mended as a gas dielectric at high operating voltages. The toxic components in sulfur hexafluoride  $SF<sub>6</sub>$  were found to appear after DBD treatment at voltages of 6 and 10 kV.

Absorbed discharge power in the DBD of a test gas characterizes the dielectric strength of the gas. The higher the absorbed power, the easier the breakdown at a given applied voltage and the lower the dielectric strength of the gas. As can be seen from Table 4, sulfur

**Table 4.** Power absorbed by DBD in test gases at different aging voltages

Reactant	$DBD$ -absorbed power, $W$				
	$U = 2$ kV	$U = 6$ kV	$U = 10$ kV		
$HFO-1234ze$	0.03	0.7			
HFO-1234yf	0.01	0.2	0.6		
C <sub>5</sub> K	0.02	0.5	3		
SF <sub>6</sub>		0.01	0.08		

hexafluoride  $SF<sub>6</sub>$  has the best dielectric strength. 2,3,3,3-tetrafluoropropene HFO-1234yf is two to three times stronger than perfluoro-3-methylbu tanone-2, and C5K is three to four times stronger than *trans*-1,3,3,3-tetrafluoropropene HFO-1234ze(E).

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